

Maximum Ratings

| Parameter | Symbol | Value | Unit |
|---|-----------|------------|------------------|
| Collector-Emitter Breakdown Voltage | V_{CE} | 1350 | V |
| DC collector current, limited by T_{jmax} $T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$ | I_C | 50 25 | A |
| Diode Forward current, limited by T_{jmax} $T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$ | I_F | 50 25 | A |
| Continuous Gate-emitter voltage | V_{GE} | ± 20 | V |
| Transient Gate-emitter voltage | V_{GE} | ± 30 | V |
| Turn off safe operating area $V_{CE} = 1350\text{V}$, $T_j = 150^\circ\text{C}$ | - | 75 | A |
| Pulsed collector current, $V_{GE} = 15\text{V}$, t_p limited by T_{jmax} | I_{CM} | 75 | A |
| Power dissipation, $T_j = 25^\circ\text{C}$ | P_{tot} | 260 | W |
| Operating junction temperature | T_j | -40...+150 | $^\circ\text{C}$ |
| Storage temperature | T_s | -55...+150 | |

Electrical Characteristics of the IGBT ($T_j = 25^\circ\text{C}$ unless otherwise specified) :

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--------------------------------------|---------------|---------------------------------|------|------|------|---------|
| Static | | | | | | |
| Collector-Emitter breakdown voltage | BV_{CES} | $V_{GE}=0V, I_C=1mA$ | 1350 | 1450 | - | V |
| | | $V_{GE}=0V, I_C=10mA$ | 1350 | 1450 | - | V |
| Gate threshold voltage | $V_{GE(th)}$ | $V_{GE}=V_{CE}, I_C=250\mu A$ | 5.1 | 5.8 | 6.4 | V |
| Collector-Emitter Saturation voltage | $V_{CE(sat)}$ | $V_{GE}=15V, I_C=25A$ | - | 2.0 | 2.5 | V |
| | | $T_j = 150^\circ\text{C}$ | - | 2.5 | - | |
| Zero gate voltage collector current | I_{CES} | $V_{CE} = 1350V, V_{GE} = 0V$ | - | <1 | 100 | μA |
| | | $T_j = 150^\circ\text{C}$ | - | - | 1000 | |
| Gate-emitter leakage current | I_{GES} | $V_{CE} = 0V, V_{GE} = \pm 20V$ | - | - | 100 | nA |
| Transconductance | g_{fs} | $V_{CE}=20V, I_C=25A$ | - | 13 | - | S |

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|------------------------------|-----------|---|-----|------|-----|------|
| Dynamic | | | | | | |
| Input capacitance | C_{ies} | $V_{CE} = 25V, V_{GE} = 0V,$ $f = 1MHz$ | - | 2500 | - | pF |
| Output capacitance | C_{oes} | | - | 70 | - | |
| Reverse transfer capacitance | C_{res} | | - | 50 | - | |
| Gate charge | Q_G | $V_{CC} = 640V, I_C = 25A,$ $V_{GE} = 15V$ | - | 135 | - | nC |

Switching Characteristic, Inductive Load

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---|--------------|---|-----|------|-----|------|
| Dynamic , at $T_j = 25^\circ \text{C}$ | | | | | | |
| Turn-off delay time | $t_{d(off)}$ | $V_{CC} = 600\text{V}, I_C = 25\text{A},$ $V_{GE} = 0/15\text{V},$ $R_g = 12\Omega$ | - | 155 | - | ns |
| Fall time | t_f | | - | 35 | - | ns |
| Turn-off energy | E_{off} | | - | 0.65 | - | mJ |
| Dynamic , at $T_j = 150^\circ \text{C}$ | | | | | | |
| Turn-off delay time | $t_{d(off)}$ | $V_{CC} = 600\text{V}, I_C = 25\text{A},$ $V_{GE} = 0/15\text{V},$ $R_g = 12\Omega$ | - | 170 | - | ns |
| Fall time | t_f | | - | 60 | - | ns |
| Turn-off energy | E_{off} | | - | 1.4 | - | mJ |

Electrical Characteristics of the DIODE ($T_j = 25^\circ \text{C}$ unless otherwise specified)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--------------------------|----------|--|-----|------|-----|------|
| Dynamic | | | | | | |
| Diode Forward Voltage | V_{FM} | $I_F = 25\text{A}$ | - | 2.3 | - | V |
| Reverse Recovery Time | T_{rr} | $I_F = 25\text{A},$ $di/dt = 200\text{A}/\mu\text{s}$ | - | 460 | - | ns |
| Reverse Recovery Current | I_{rr} | | - | 17 | - | A |
| Reverse Recovery Charge | Q_{rr} | | - | 3600 | - | nC |



YGW25N135F1A

Fig. 1 FF

Fig. 2 Load Current vs. Frequency

Fig. 5 Typical Saturation Voltage vs. Junction Temperature

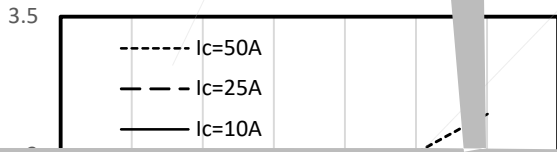


Fig. 6 Typical Diode Forward Characteristics

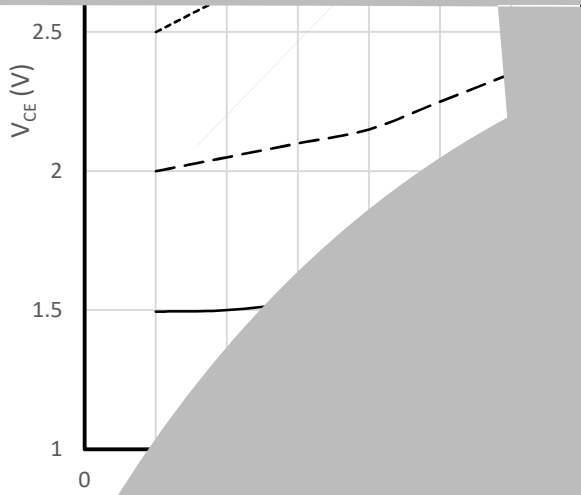
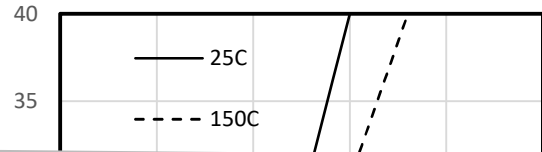


Fig. 7 T

YGW25N135F1A

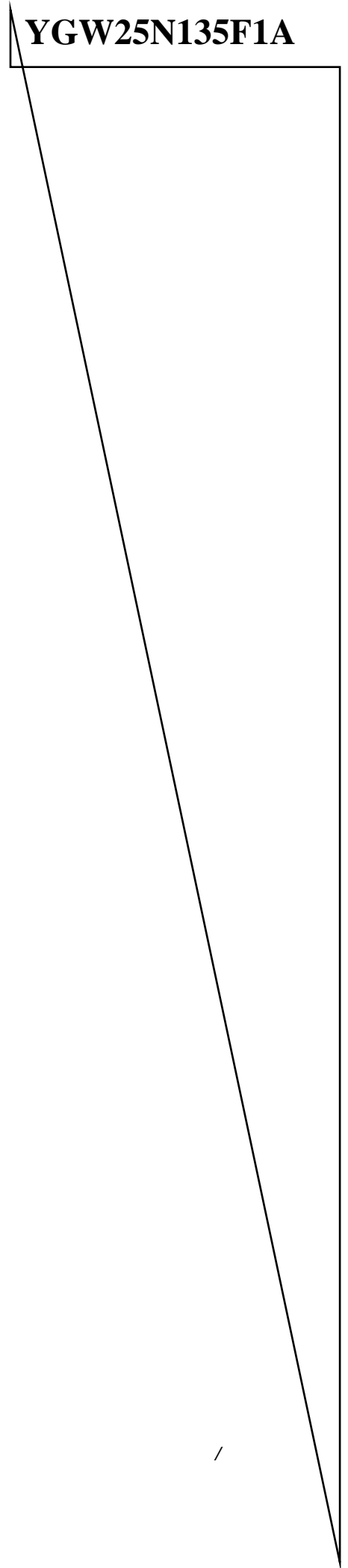


Fig. 13 Capacitance characteristics

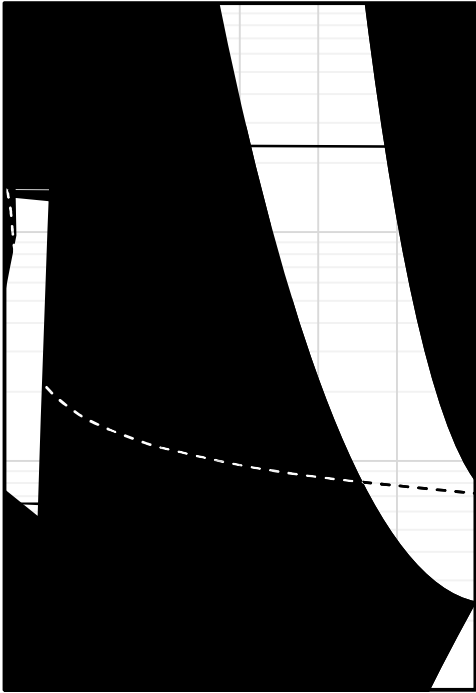
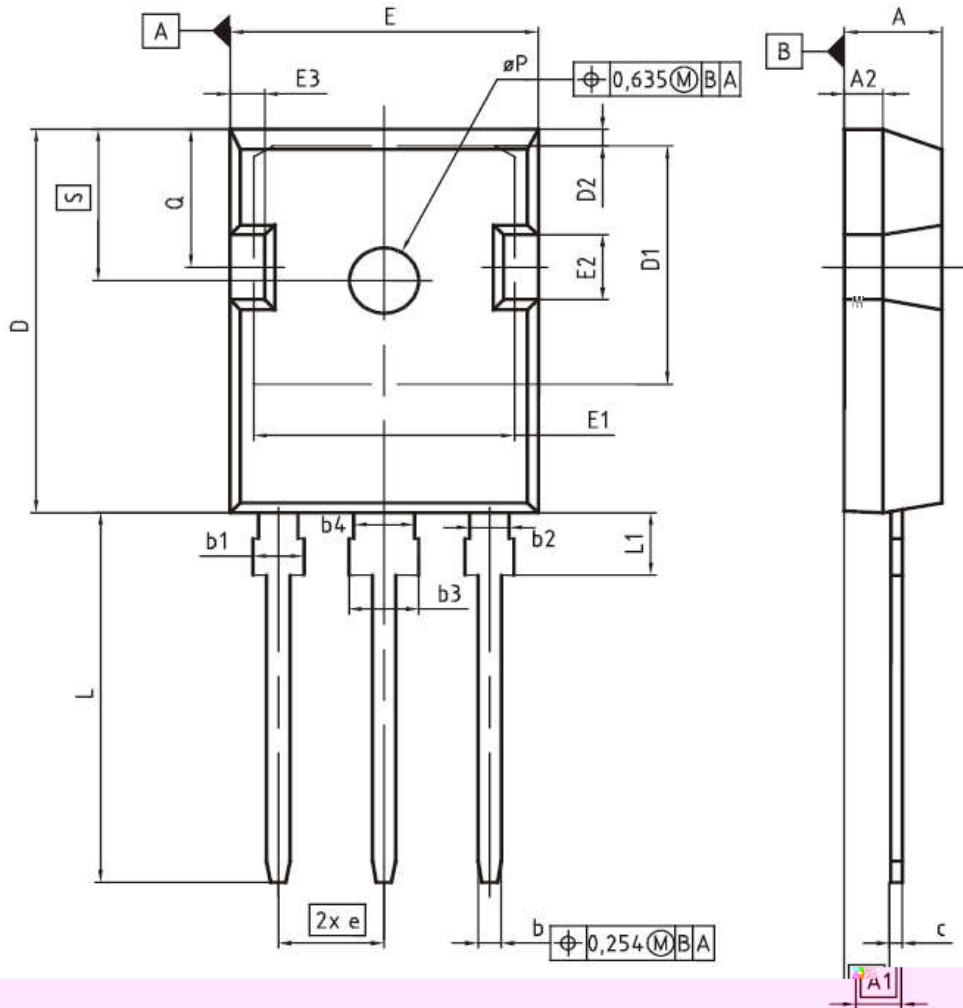


Fig. 14 Gate charge characteristics

Fig. 15 IGBT Transient Thermal Impedance

PG-TO247-3



| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 4.83 | 5.21 | 0.190 | 0.205 |
| A1 | 2.27 | 2.54 | 0.089 | 0.100 |
| A2 | 1.85 | 2.16 | 0.073 | 0.085 |
| b | 1.07 | 1.33 | 0.042 | 0.052 |
| b1 | 1.90 | 2.41 | 0.075 | 0.095 |
| b2 | 1.90 | 2.16 | 0.075 | 0.085 |
| b3 | 2.87 | 3.38 | 0.113 | 0.133 |
| b4 | 2.87 | 3.13 | 0.113 | 0.123 |
| c | 0.55 | 0.68 | 0.022 | 0.027 |
| D | 20.80 | 21.10 | 0.819 | 0.831 |
| D1 | 16.25 | 17.65 | 0.640 | 0.695 |

| DIM | MIN | MAX | MIN | MAX |
|-----|------|------|-------|-------|
| D2 | 1.50 | 1.75 | 0.059 | 0.069 |
| E | 1.50 | 1.75 | 0.059 | 0.069 |
| E1 | 1.50 | 1.75 | 0.059 | 0.069 |
| E2 | 1.50 | 1.75 | 0.059 | 0.069 |
| E3 | 1.50 | 1.75 | 0.059 | 0.069 |
| L | 1.50 | 1.75 | 0.059 | 0.069 |
| L1 | 1.50 | 1.75 | 0.059 | 0.069 |
| S | 1.50 | 1.75 | 0.059 | 0.069 |
| a | 1.50 | 1.75 | 0.059 | 0.069 |
| d | 1.50 | 1.75 | 0.059 | 0.069 |
| e | 1.50 | 1.75 | 0.059 | 0.069 |
| p | 1.50 | 1.75 | 0.059 | 0.069 |